

DUAL HIGH PERFORMANCE OPERATIONAL AMPLIFIER**SE/NE5512****DESCRIPTION**

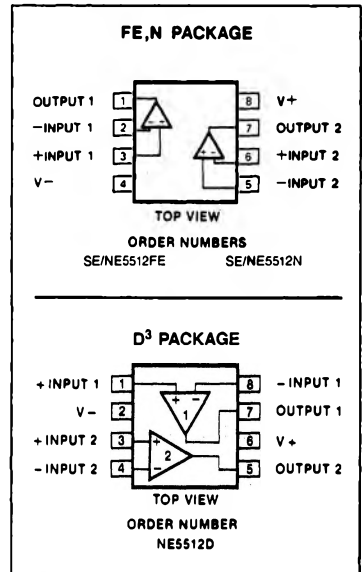
The 5512 series of high performance operational amplifier provides very good input characteristics. These amplifiers feature low input bias and voltage characteristics such as a 108 op amp with improved CMRR and a high differential input voltage limit achieved through the use of a bias cancellation and PNP input circuits with collector to emitter clamping. The output characteristics are like those of a 741 op amp with improved slew rate and drive capability yet have low supply quiescent current.

APPLICATIONS

- AC amplifiers
- RC active filters
- Transducer amplifiers
- DC gain block
- Battery operation
- Instrumentation amplifiers

FEATURES

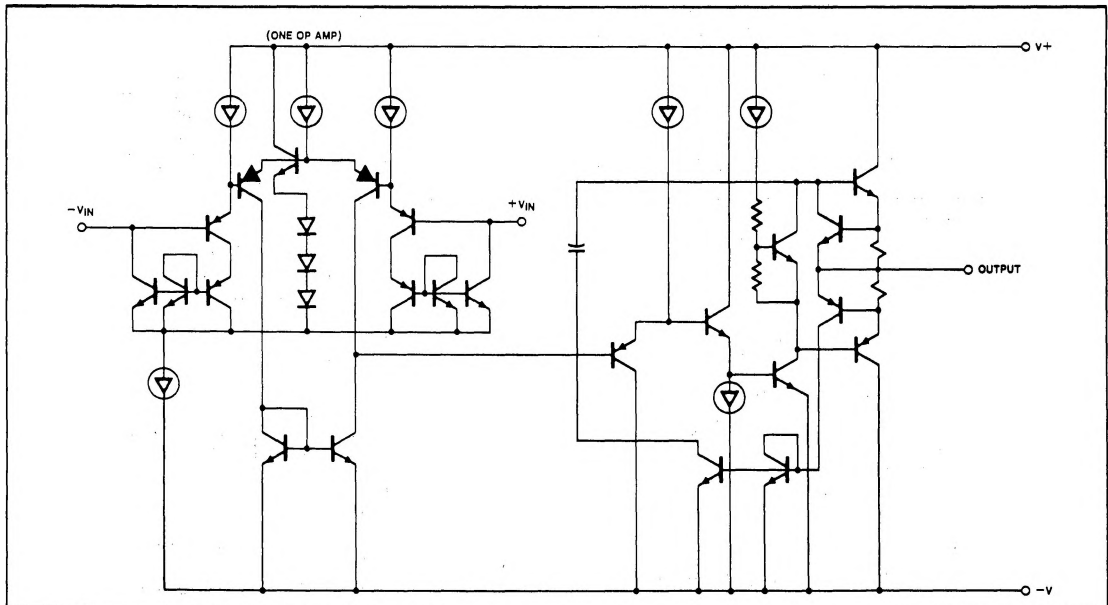
- Low input bias $< \pm 20\text{nA}$
- Low input offset current $< \pm 20\text{nA}$
- Low input offset voltage $< 1\text{mV}$
- Low V_{OS} temperature drift $5\mu\text{V}/^\circ\text{C}$
- Low input bias temperature drift $40\text{pA}/^\circ\text{C}$
- Low input voltage noise $30\text{nV}/\sqrt{\text{Hz}}$
- Low supply current $1.5\text{mA}/\text{amp}$
- High slew rate $1.0\text{V}/\mu\text{s}$
- High CMRR 100dB
- High PSRR 110dB
- High input impedance $100\text{M}\Omega$
- High PSRR 110dB
- High differential input voltage limit
- No cross-over distortion
- Indefinite output short circuit protection
- Internally compensated for unity gain
- 600Ω drive capability

PIN CONFIGURATIONS**NOTES:**

1. SOL - Released in large SO package only.
2. SOL and non-standard pinout.
3. SO and non-standard pinouts.

ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Unit
V_{CC} Supply Voltage	± 16	V
P_D Power dissipation	500	mW
T_A Operating temperature range		
NE5512	0 to 70	$^\circ\text{C}$
SE5512	-55 to +125	$^\circ\text{C}$
T_{STG} Storage temperature range	-65 to +150	$^\circ\text{C}$
T_{SOLD} Lead temperature soldering	300	$^\circ\text{C}$

EQUIVALENT SCHEMATIC

DUAL HIGH PERFORMANCE OPERATIONAL AMPLIFIER

SE/NE5512

ELECTRICAL PERFORMANCE CHARACTERISTICS $V_{CC} = \pm 15V$, F.R. = $-55^{\circ}C$ to $+125^{\circ}C$ (SE), $0^{\circ}C$ to $+70^{\circ}C$ (NE)

	PARAMETER	TEST CONDITIONS	SE5512			NE5512			UNIT
			Min	Typ	Max	Min	Typ	Max	
V_{OS}	Input offset voltage	$R_S = 100\Omega$ $T_A = +25^{\circ}C$ $T_A = F.R.$ Over Temp.		0.7 1 4	2 3		1 1.5 5	5 6	mV $\mu V/^{\circ}C$
ΔV_{OS}									
I_{OS}	Input offset current	$R_S = 100k\Omega$ $T_A = +25^{\circ}C$ $T_A = F.R.$ Over Temp.		3 4 30	10 20		6 8 40	20 30	nA $pA/^{\circ}C$
ΔI_{OS}									
I_B	Input bias current	$R_S = 100k\Omega$ $T = +25^{\circ}C$ $T_A = F.R.$ Over Temp.		3 4 30	10 20		6 8 40	20 30	nA $pA/^{\circ}C$
ΔI_B									
R_{IN}	Input resistance differential	$T_A = 25^{\circ}C$		100			100		M Ω
V_{CM}	Input common mode range	$T_A = 25^{\circ}C$ $T_A = F.R.$	± 13.5 ± 13	± 13.7 ± 13.2		± 13.5 ± 13	± 13.7 ± 13.2		V
CMRR	Input common-mode rejection ratio	$V_{CC} = \pm 15V$ $V_{IN} = \pm 13.5V$ (RM) $T_A = 25^{\circ}C$ $V_{IN} = \pm 13V$ (F.R.) $T_A = F.R.$	70	100		70	100		dB
A_{VOL}	Large-signal voltage gain	$R_L = 2k\Omega$ $T_A = 25^{\circ}C$ $V_O = \pm 10V$ $T_A = F.R.$	50 25	200		50 25	200		V/mV
S.R.	Slew rate	$T_A = 25^{\circ}C$	0.6	1			1		V/ μs
GBW	Small-signal unity gain bandwidth	$T_A = 25^{\circ}C$		3			3		MHz
θ_M	Phase margin	$T_A = 25^{\circ}C$		45			45		Degree
V_{OUT}	Output voltage swing	$R_L = 2k\Omega$ $T_A = 25^{\circ}C$ $T_A = F.R.$	± 13 ± 12.5	± 13.5 ± 13		± 13 ± 12.5	± 13.5 ± 13		V
V_{OUT}	Output voltage swing	$R_L = 600\Omega^*$ $T_A = 25^{\circ}C$ $T_A = F.R.$	± 10 ± 7.5	± 11.5 ± 9		± 10 ± 8	± 11.5 ± 9		V
I_{CC}	Power supply current	$R_L = \text{Open}$ $T_A = 25^{\circ}C$ $T_A = F.R.$		3.4 3.6	5 5.5		3.4 3.6	5 5.5	mA
P_{SRR}	Power supply rejection ratio	$T_A = 25^{\circ}C$ $T_A = F.R.$	80 80	110 100		80 80	110 100		dB
AA	Amplifier to amplifier coupling	$f = 1kHz$ to $20kHz$ $T_A = 25^{\circ}C$		-120			-120		dB
HD	Total harmonic distortion	$f = 10kHz$ $T_A = 25^{\circ}C$ $V_O = 7V_{RMS}$		0.01			0.01		%
V_{INN}	Input noise voltage	$f = 1kHz$ $T_A = 25^{\circ}C$		30			30		nV/ $\sqrt{Hz}$
I_{IN}	Input noise current	$f = 1kHz$ $T_A = 25^{\circ}C$		.2			.2		pA/ $\sqrt{Hz}$
I_{SC}	Short circuit	$\pm 15V$ $T_A = 25^{\circ}C$		40			40		mA

NOTE

For operation at elevated temperature, N package must be derated based on a thermal resistance of 120 $^{\circ}W$ /junction to ambient. Thermal resistance of the FE package is 125 $^{\circ}W$.

*For additional information, consult the Applications Section.